### HCPL2601 OPTOCOUPLER/OPTOISOLATOR

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- Gallium Arsenide Phosphide LED Optically Coupled to an Integrated Circuit Detector
- Internal Shield for Common-Mode Rejection
- Compatible with TTL and LSTTL Inputs
- Low Input Current Required to Turn Output On . . . 5 mA Max
- High-Voltage Electrical Insulation . . . 3000 V DC Min
- High-Speed Switching . . . 75 ns Max
- UL Recognized . . . File Number E65085
- Directly Interchangeable with Hewlett
   Packard HCPL2601

#### description

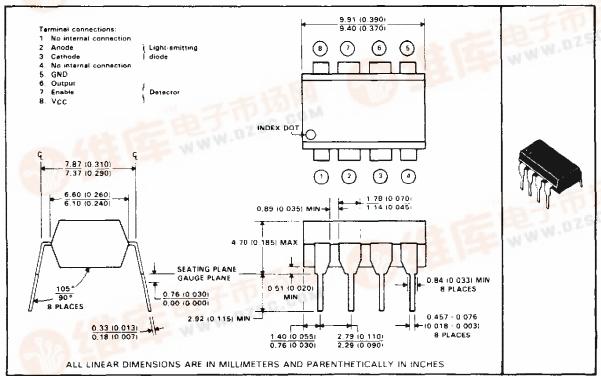
The HCPL2601 optocoupler is designed for use in high-speed digital interfacing applications that require high-voltage isolation between the input and output. It is recommended for use in extremely high ground-noise and induced-noise environments. Applications include line receivers, microprocessors or computer interface, digital programming of floating power supplies, motors, and other control systems.

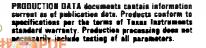
The HCPL2601 high-speed optocoupler consists of a GaAsP light-emitting diode and an integrated light detector composed of a photodiode, a high-gain amplifier, and a Schottky-clamped open-collector output transistor. An input diode forward current of 5 milliamperes will switch the output transistor low, providing an on-state drive current of 13 milliamperes (eight 1.6-milliampere TTL loads). A TTL-compatible enable input is provided for applications that require output-transistor gating.

The HCPL2601 is mounted in a standard 8-pin dual-in-line plastic package.

The HCPL2601 is characterized for operation over the temperature range of 0 °C to 70 °C. The internal shield provides a guaranteed common-mode transient immunity of 1000 volts/microsecond minimum.

### mechanical data





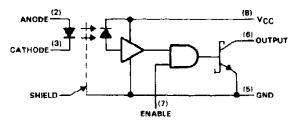


## HCPL2601 OPTOCOUPLER/OPTOISOLATOR

### FUNCTION TABLE

INPUT	ENASLE	OUTPUT
IF(on)	н	Ĺ
IF(off)	×	н
x	L	н

## logic diagram (positive logic)



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC
Reverse input voltage
Enable input voltage (not to exceed VCC by more than 500 mV)
Output voltage
Peak forward input current (≤ 1 ms duration)40 mA
Average forward input current
Output current
Output power dissipation
Storage temperature range55 °C to 125 °C
Operating free-air temperature range
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds

## recommended operating conditions

		MIN	NOM MAX	UNIT
Vcc	Output supply voltage (see Note 1)	4.5	5 5.5	V
VIH(EN)	High-level enable input voltage (see Note 2)	2	VCC	V
VIL(EN)	Low-level enable input voltage	0	0.8	· V
IF(on)	Input forward current to turn output on	6.3	15	mA
<sup>1</sup> F(off)	Input forward current to turn output off	0	250	μA
loL	Low-level (on-state) output current		13	mA
TA	Operating free-air temperature	0	70	°C

NOTES: 1. All voltage values are with respect to GND Ipin 5).

2. No external pullup is required at the enable input; an open circuit will establish the high level.

# **HCPL2601** OPTOCOUPLER/OPTOISOLATOR

### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER V <sub>F</sub> Input forward voltage		TEST CONDITIONS		MIN	TYP <sup>†</sup> 1.6	MAX 1.75	UNIT
		Ip = 10 mA, TA = 25°C					
αVF	Temperature coefficient of forward voltage	IF = 10 mA	· · · · · ·		-1.8		mV/°C
VBR	Input reverse breakdown voltage	$i_R = 10 \mu A$ ,	T <sub>A</sub> = 25°C	5			V
You	Low-level output voltage	V <sub>CC</sub> = 5.5 V, I <sub>F</sub> = 5 mA,			0.23	0.6	V
lон	High-level output current	1	V <sub>O</sub> = 5.5 V, I <sub>F</sub> = 250 μA			250	μА
JH(EN)	High-level enable input current	V <sub>CC</sub> = 5.5 V.	V(EN) = 2 V		-0.2		mA
IL(EN)	Low-level enable input current	V <sub>CC</sub> = 5.5 V,	V <sub>(EN)</sub> = 0.5 V		-0.5	- 2	mΑ
Іссн	Supply current, high-level output	V <sub>CC</sub> = 5.5 V,	$V_{(EN)} = 0.5 V,$		10	15	mA
<sub>I</sub> CCL	Supply current, low-level output	V <sub>CC</sub> = 5.5 V, I <sub>F</sub> = 10 mA	$V_{(EN)} = 0.5 V,$		13	19	mA
lio	Input-putput insulation leakage current	V <sub>IO</sub> = 3000 V, T <sub>A</sub> = 25 °C, See Note 1				1	μА
סוי	Input-output resistance	V <sub>IO</sub> = 500 V, See Note 1	₹ <sub>A</sub> = 25°C.		1012		Ω
Ci	Input capacitance	Vr = 0,	f = 1 MHz		60		pF
Cia	Input-output capacitance	f = 1 MHz, See Note 1	T <sub>A</sub> = 25°C,		0.6		pF

 $^{T}$  All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25 °C. NOTE 1: These parameters are measured between pins 2 and 3 shorted together and pins 5, 6, 7, and 8 shorted together.

# switching characteristics at $V_{CC} = 5 \text{ V}$ , $T_A = 25 \text{ °C}$

	PARAMETER	TEST	CONDITIONS	MIN TY	MAX	UNIT
<sup>†</sup> PLH	Propagation delay time, low-to-high level output, from LED input	l <sub>F</sub> = 7.5 mA, C <sub>L</sub> = 15 pF,	R <sub>L</sub> = 350 Ω. See Figure 1	42	? 75	ns
tp <sub>HL</sub>	Propagation delay time, high-to-low level output, from LED input	Ip = 7.5 mA, Ct = 15 pF,	$H_L = 350 \Omega$ . See Figure 1	42	75	ns
<sup>†</sup> PLH(EN)	Propagation delay time, low-to-high level output, from enable	lp = 7 5 mA, C <sub>L =</sub> 15 pF,	R <sub>L</sub> = 350 Ω. See Figure 2	4(	)	ns
<sup>t</sup> PHL(EN)	Propagation delay time, high-to-low level output, from enable	l <sub>F</sub> = 7.5 mA, C <sub>L</sub> - 15 pF,	$R_L = 350 \Omega$ . See Figure 2	25	5	ns
t <sub>f</sub>	Rise time	i <sub>F</sub> = 7.5 mA, C <sub>L</sub> = 15 pF	$R_L = 350 \Omega$ .	20	)	ns
tf	Fall time	lp = 7.5 mA, CL = 15 pF	$R_L = 350 \Omega$ .	30	)	ns
dVCM (H)	Common-mode input transient immunity, high-level output	$\Delta V_{CM} = 50 \text{ V},$ $R_L = 350 \Omega.$	(F = 0. See Note 2 and Figure 3.	1000 10000	)	V/μs
$\frac{dV_{CM}}{dt}$ (L)	Common-mode input transient immunity, low-level output	$\Delta V_{CM} = -50 \text{ V}.$ $R_L = 350 \Omega,$	IF = 7.5 mA. See Note 2 and Figure 3	- 1000 1000	)	V/μs

NOTE 2: Common-mode input transient immunity, high-level output, is the maximum rate of rise of the common-mode input voltage that does not cause the output voltage to drop below 2 V. Common-mode input transient immunity, low-level output, is the maximum rate of fall of the common mode input voltage that does not cause the output voltage to rise above 0.8 V.



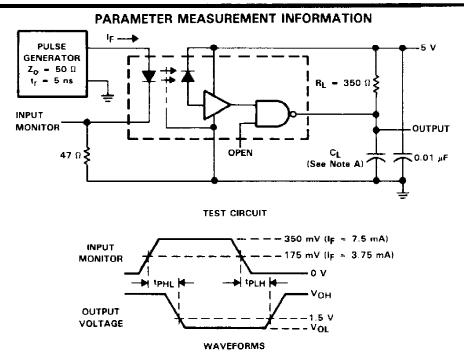


FIGURE 1. tPLH AND tPHL FROM LED INPUT TEST CIRCUIT AND WAVEFORMS

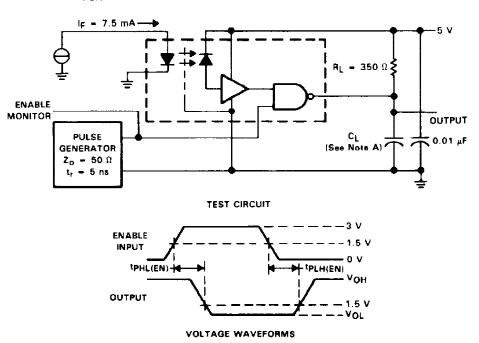
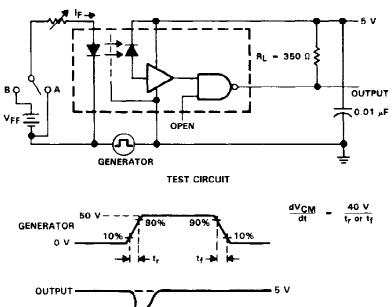


FIGURE 2. tpLH(EN) AND tpHL(EN) FROM ENABLE TEST CIRCUIT AND WAVEFORMS

NOTE A: CL is approximately 15 pF, which includes probe and stray wiring capacitances.



# PARAMETER MEASUREMENT INFORMATION



SWITCH AT A: IF = 0 OUTPUT -SWITCH AT B: Ip = 7.5 mA

**VOLTAGE WAVEFORMS** 

FIGURE 3. TRANSIENT IMMUNITY TEST CIRCUIT AND WAVEFORMS

### TYPICAL APPLICATION INFORMATION

A ceramic capacitor (0.01 µF to 0.1 µF) should be connected between pins 8 and 5 to stabilize the highgain amplifier. The total lead length between the capacitor and the optocoupler should not exceed 20 mm (0.8 inches). Failure to provide a bypass capacitor may result in impaired switching characteristics.

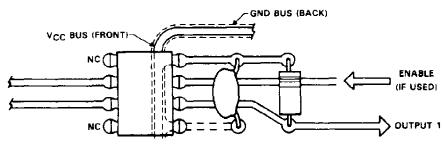


FIGURE 4. RECOMMENDED PRINTED CIRCUIT BOARD LAYOUT

## TYPICAL CHARACTERISTICS



FORWARD VOLTAGE 20 TA = 25°C 18 16 IF - Forward Current -- mA 14 12 10 6 4 2 O 1.2 1.6 1.7 VF-Forward Voltage-V

FIGURE 5

# LOW-LEVEL OUTPUT VOLTAGE

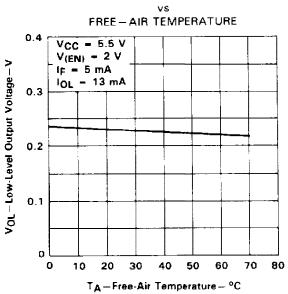


FIGURE 6

# HIGH-LEVEL OUTPUT CURRENT

FREE-AIR TEMPERATURE

4

V<sub>CC</sub> = 5.5 V

V<sub>O</sub> = 5.5 V

I<sub>F</sub> = 250 μA

3

0 10 20 30 40 50 60 70 80

T<sub>A</sub>-Free-Air Temperature – °C

FIGURE 7

## **TYPICAL CHARACTERISTICS**

PROPAGATION DELAY TIME FROM LED INPUT

vs PULSE FORWARD CURRENT

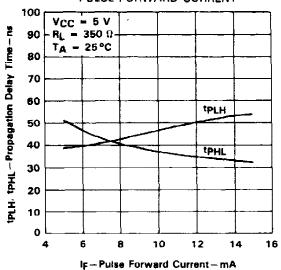


FIGURE 8

PROPAGATION DELAY TIME FROM LED INPUT

LOAD RESISTANCE

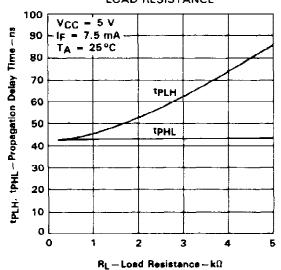


FIGURE 9

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